

Ku Band 2W Packaged Amplifier

TGA8658-EPU-SG



Package Dimensions 6.4 x 6.4 x 3.0 mm

Key Features

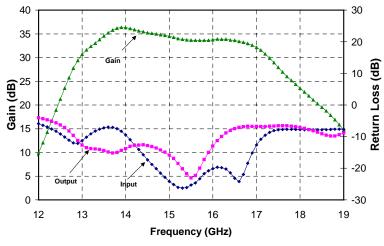
- Frequency Range: 13-17 GHz
- Optimized for VSAT band (13.75-14.5GHz)
- 33 dB Nominal Gain
- Typical > 33.5 dBm Psat in VSAT band @ 7V
- Bias 5-8 V @ 680 mA (Quiescent)
- 0.5 μm 3MI pHEMT Technology
- Integrated power detector
- 6 lead package
- Package Dimensions: 6.4 x 6.4 x 3.0 mm (0.3 x 0.3 x 0.1 in)

Primary Applications

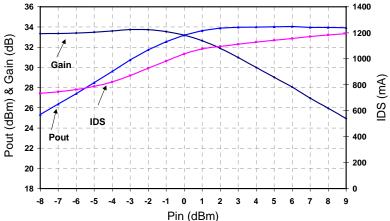
- VSAT
- Point-to-Point

Fixtured Measured Performance

Bias Conditions: Vd = 7 V, Idq =680 mA



Data taken @ 14.5 GHz





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TABLE I MAXIMUM RATINGS <u>1/</u>

Symbol	Parameter	Value	Notes
Vd	Drain Supply Voltage	8 V	<u>2</u> /
Vg	Gate Supply Voltage Range	-5V to 0V	
ldq	Drain Supply Current (Quiescent)	1.3 A	<u>2</u> /
lg	Gate Current	18 mA	
P _{IN}	Input Continuous Wave Power	21 dBm	<u>2</u> /
P_D	Power Dissipation	5 W + (85°C- T _B)/13	<u>2</u> / <u>3</u> /
T _{CH}	Operating Channel Temperature	150 °C	<u>4</u> / <u>5</u> /
T _M	Mounting Temperature (30 Seconds)	320 °C	
T _{STG}	Storage Temperature	-65 to 150 °C	

- 1/ These ratings represent the maximum operable values for this device.
- 2/ Combinations of supply voltage, supply current, input power, and output power shall not exceed P_D.
- 3/ T_B = Package backside temperature in degrees C.
- 4/ These ratings apply to each individual FET.
- 5/ Junction operating temperature will directly affect the device median time to failure (T_M). For maximum life, it is recommended that junction temperatures be maintained at the lowest possible levels.

TABLE II RF CHARACTERIZATION TABLE ($T_A = 25$ °C, Nominal) (Vd = 7 V, Idq = 680 mA)

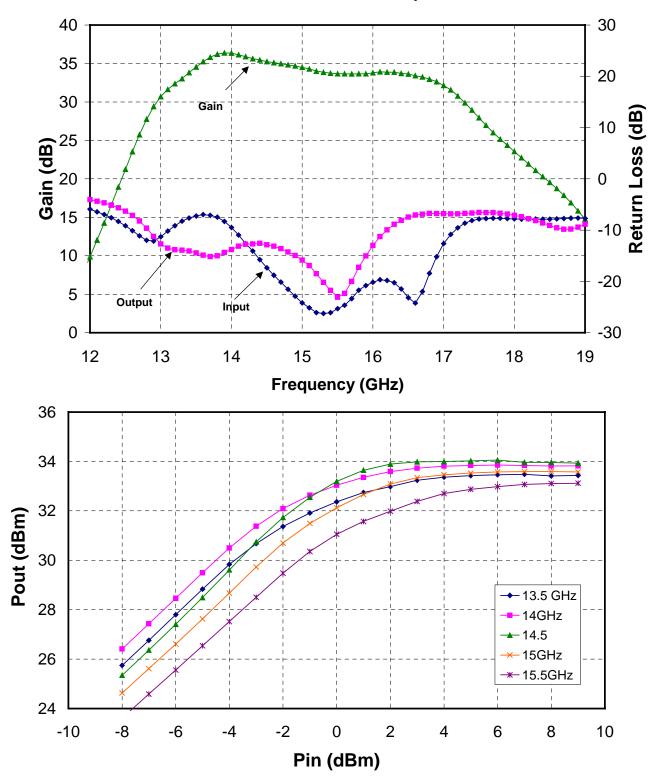
SYMBOL	PARAMETER	TEST CONDITION	TYPICAL	UNITS
Gain	Small Signal Gain	F = 13 –17 GHz	33	dB
IRL	Input Return Loss	F = 13 –17 GHz	10	dB
ORL	Output Return Loss	F = 13 –17 GHz	10	dB
PWR	Output Power @ Pin = +5 dBm	F = 13 –15 GHz	34	dBm



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Measured Fixtured Data

Bias Conditions: Vd = 7 V, Idq = 680 mA

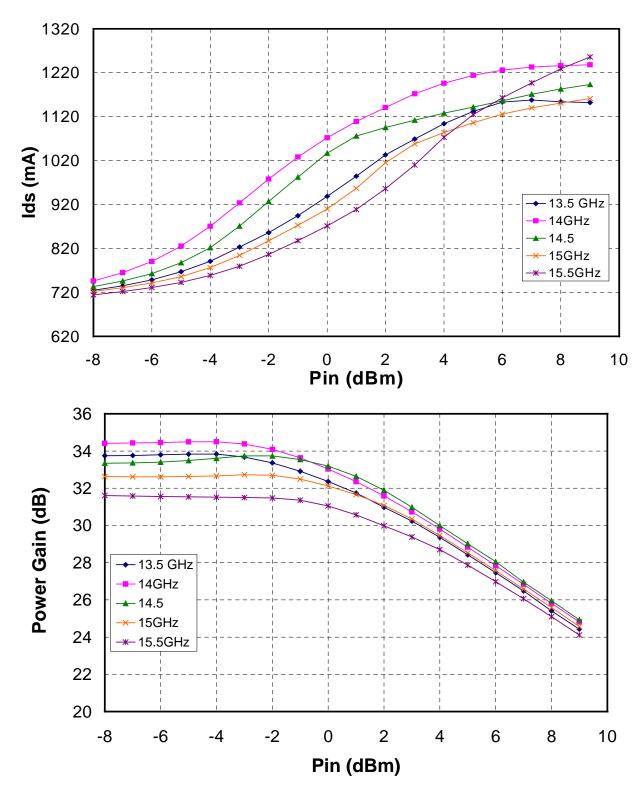




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Measured Fixtured Data

Bias Conditions: Vd = 7 V, Idq = 680 mA

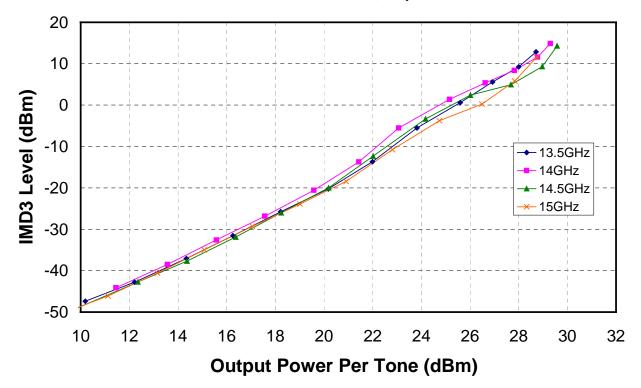




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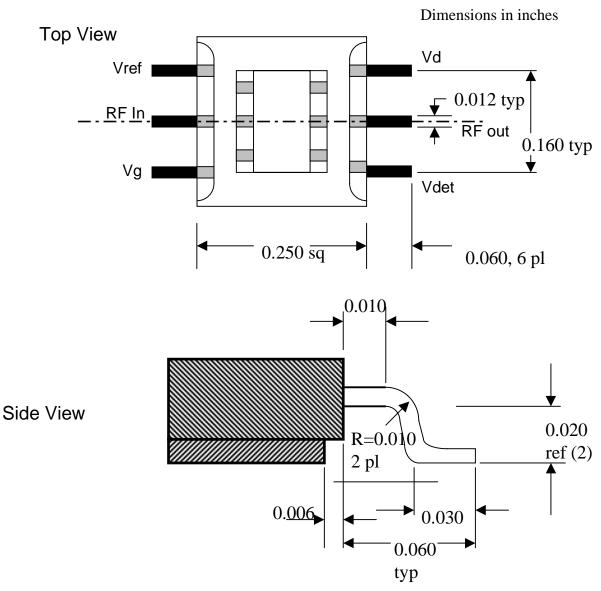
Measured Fixtured Data

Bias Conditions: Vd = 7 V, Idq = 680 mA





Packaged Dimensional Drawing TGA8658 - SG



Bias Procedure

- 1. Make sure no RF power is applied to the device before continuing.
- 2. Pinch off device by setting V_G to -1.5V.
- 3. Raise Vd to 7.0V while monitoring drain current.
- 4. Raise V_g until drain current reaches 680 mA.
- 5. Apply RF power.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



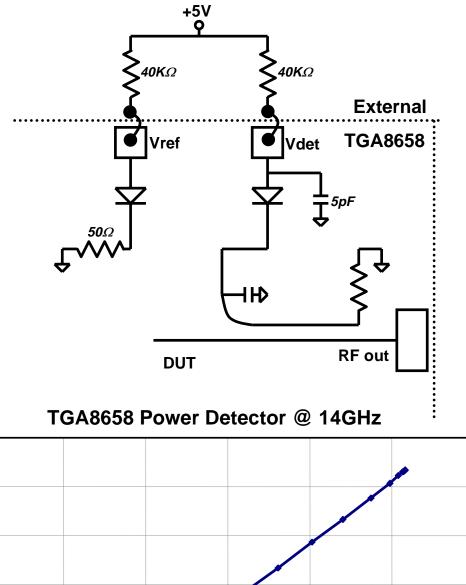
0.6

0.5

Advance Product Information

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Power Detector



0.4 10 0.2 0.1 0 10 (20 dBm) (26 dBm) (29.5 dBm) (32 dBm) (34 dBm) sqrt Pout (mW^0.5)



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Assembly of a TGA8658-EPU-SG Surface Mount Package onto a Motherboard

Manual Assembly for Prototypes

- 1. Clean the motherboard or the similar module with Acetone. Rinse with alcohol and DI water. Allow the circuit to fully dry.
- 2. To improve the thermal and RF performance, we recommend a heat sink attach to the bottom of the package and apply indium alloy SN63 solder or Tin Lead solder to the bottom of TGA8658.
- 3. Apply Tin Lead solder to each pin of TGA8658.
- 4 Clean the assembly with alcohol.

High Volume Assembly of the Package

The TGA8658EPU is a custom leaded packaged component. High volume assembly can be performed using standard assembly processes including solder printing such as stencil solder printing. Pick-and-place using a standard machine such as a MRSI machine, and solder reflow using a "Sikama Reflow System" using typical zone temperatures: 120, 175, 195, and 215 degrees Celsius at 15 second intervals.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.